

Interfacial Intermetallic Growth and Strength of Composite Lead-Free Solder Alloy Through Isothermal Aging

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The effects of particle reinforcement of Sn-4.0wt.%Ag-0.5wt.%Cu (SAC405) lead-free solder on interfacial intermetallic layer growth and strength of the ensuing joints through short-term isothermal aging (150°C) were studied. Composite solders were prepared by either incorporating 2 wt.% Cu (3 μm to 20 μm) or Cu₂O (~150 nm) particles into SAC405 paste. Aggressive flux had the effect of reducing the Cu₂O nanoparticles into metallic Cu which subsequently reacted with the solder alloy to form the Cu₆Sn₅ intermetallic. While all solders had similar interfacial intermetallic growth upon reflow, both of the composite solders' growth rates slowed through aging to reach a common growth rate exponent of approximately 0.38, considerably lower than that of the nonreinforced solder ($n = 0.58$). The nanoscale reinforced solder additionally exhibited the highest tensile strength in both the initial and aged conditions, behavior also attributed to its quick conversion to a stable microstructure.

Key words: Lead-free solder, nanocomposite, aging, intermetallic compounds, tension test

INTRODUCTION

Tin (Sn)-rich lead-free solders are currently the predominant interconnection material for the microelectronics industry. The resulting interconnect provides both electrical and mechanical connection between integrated circuit devices and their substrate.¹ Existing lead-free solders are not drop-in substitutes for conventional lead-bearing solders, however, as they have yet to match or surpass current reliability standards.² During the soldering process molten solder wets and reacts with the metallization of the substrate to form a metallurgical bond by the formation of intermetallic compounds.³ While adequate formation of this intermetallic layer is essential for good bonding, an overly thick layer promotes a brittle failure mode at

this interface.⁴ The thickening of this layer is due to the constant and inevitable diffusion of Sn from the bulk solder to the substrate primarily during service at high homologous temperatures. Therefore it is of current interest to limit the growth of the interfacial intermetallic such that an optimum layer thickness is achieved: one that ensures a robust bond yet is not conducive to a brittle failure mode. One approach researchers have adopted for this purpose is the composite method, in which suitable particles are introduced to stabilize the solder's microstructure.⁵ The overall objective of the current study is to investigate the effect of adding reactive particles to the solder alloy on the subsequent growth of the interfacial intermetallic layer and the ensuing joint's tensile strength.

To address this objective, two composite solders (solder alloy with additional particles) were fabricated for comparison against the unreinforced alloy through aging at 150°C for up to 1 week. Either

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micrometer-scale Cu or nanometer-scale Cu_2O particles were employed as the reinforcement particles to subsequently produce additional Cu-Sn intermetallic reinforcing phases. The expectation is that the large difference in initial particle size of this additional source of Cu will help to elucidate the rate-limiting mechanism of the interfacial intermetallics growth. Cu was also chosen as a reinforcement to increase joint strength without sacrificing ductility; the relatively weak interfacial bonding between Cu-Sn particles and the solder matrix, compared with Ni or inorganic particles for example, is expected to allow more homogenous deformation of the solder joint, therefore preserving its ductility within a range similar to unreinforced Sn-rich lead-free solders.⁶⁻⁸ In the current study the mechanical mixing of nanometer-sized Cu_2O particles is also sought as an alternative to the difficult *in situ* preparation of composite solders. It is demonstrated that, while a similarly reduced steady state of intermetallic growth is obtained for the two composite samples, it is achieved sooner in the one fabricated with the nanometer-scale particles. Mechanical test results indicate that the composite specimen prepared with nanometer-scale particles also provides the highest tensile strength both before and after aging. A discussion on the implications of these results on the current understanding of composite solder behavior follows.

MATERIALS AND EXPERIMENTAL PROCEDURE

Three aging specimens were prepared for the current study: one with a reference and two with composite solders. The lead-free solder alloy Sn-4.0wt.%Ag-0.5wt.%Cu (SAC405, Alpha Metals) in the form of solder paste was used for the reference specimen and as the matrix material for the two composite solders. The composite solders were prepared by adding either 2 wt.% micrometer-scale commercial Cu particles (3 μm to 20 μm , 99.9% purity, Leico Industries) or nanometer-scale polyvinylpyrrolidone-coated copper oxide particles ($\text{Cu}_2\text{O}/\text{PVP}$) to the solder paste with a simple mechanical mixing method.⁹ The $\text{Cu}_2\text{O}/\text{PVP}$ particles were synthesized via a chemical reduction route and analyzed for size and composition with electron microscopy and powder x-ray diffraction.¹⁰ Aging specimens were fabricated by reflowing the prepared solders on Cu substrates (3 cm \times 2 cm \times 0.2 cm) first polished to a 1000 grit size, degreased, pickled in a 5% HCl solution, rinsed in deionized water, and blown dry. The reaction surface area of the substrates and the amount of solder paste were fixed for each specimen. Reflow soldering was conducted in a Zelflow RO4 oven (LPKF Electronics) with a temperature profile consisting of a 150°C preheating stage followed by a peak temperature of 240°C. The specimens were reflowed individually and removed from the oven to cool in air. Following

initial reflow, the specimens were aged in a 150°C oven and analyzed at regular intervals of 24 h for up to 1 week. At these intervals the specimens were sectioned, polished to a 0.6- μm finish with a suspension of alumina and etched with 5% HCl in methanol to highlight the intermetallic phases. Scanning electron microscopy (SEM) with energy-dispersive spectroscopy (EDS) was used to characterize the intermetallic phases and provide micrographs for subsequent image analysis.

The micrographs were analyzed for intermetallic layer thickness at the substrate/solder interface. Average thickness measurements were made using Image-Pro Plus software by dividing the area of the interfacial intermetallic layer by its length. The accuracy of this average measurement was estimated to be $\pm 0.25 \mu\text{m}$, dictated by the ability to resolve this boundary in the magnified images. At least two measurements were made for each specimen and condition.

The mechanical test specimens were produced in the following way. Cu plates were machined to produce symmetrical substrates of dimensions 60 mm \times 20 mm \times 1 mm. A rectangular butt joint was then produced by affixing the substrates in a custom soldering jig that fixed the gap thickness to 0.5 mm, chosen to keep the influence of constraining effects on the resulting mechanical response of the solder joint to a minimum.¹¹ The three solder pastes of interest were prepared as previously described, and used as a filler material between the fixed substrates. The solder was reflowed, and joints produced, by placing the entire soldering assembly (jig with affixed substrates and solder) in the reflow oven and subjecting it to an identical temperature profile as that applied to the aging specimens. Once removed from the jig, the test specimens were ground to remove any excess solder and to fix the width of the joining layer to approximately 0.98 mm (Fig. 1). The resulting specimens were then portioned to receive isothermal heat treatments again identical to the 24 h condition of the aging specimens. A total of 24 specimens were produced: four for each solder and aging condition.

The specimens were tested in uniaxial tension. All testing was performed by using an Instron 5848 Micro Tester at a displacement rate of 30 $\mu\text{m}/\text{min}$. A sequence of high-resolution images of the joints was recorded during the test through an optical microscope at magnifications of 24 \times to 48 \times . The recorded sequences were then processed in custom-developed digital image correlation (DIC) software to calculate the evolution of the average strain in the solder during the test.⁸ This technique enables strain resolution in the joint of approximately 0.02%.

RESULTS

The synthesized copper oxide particles were confirmed to be Cu_2O by powder x-ray diffraction (XRD) (Fig. 2). The five peaks of the x-ray spectrum

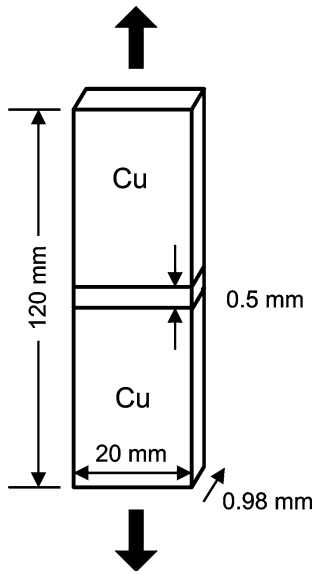


Fig. 1. Schematic of mechanical test specimen and loading direction.

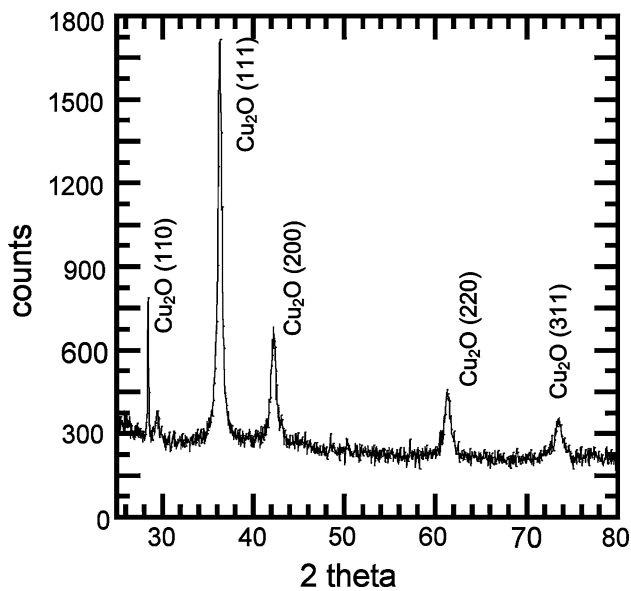


Fig. 2. XRD pattern for synthesized nanometer-scale Cu_2O particles.

correspond to the interplanar spacings of 3.02 Å, 2.46 Å, 2.13 Å, 1.5 Å, and 1.28 Å, consistent with the Cu_2O cubic phase powder diffraction standard.¹² The lattice constant calculated for this set of planes is 4.25 Å, a value in agreement with Cu_2O .¹³

Transmission electron microscopy (TEM) images illustrated that the particles were of cubic morphology and the associated electron diffraction pattern confirmed their single-crystalline nature (Fig. 3). Also visible in the TEM image is the protective PVP cap, appearing as a light halo around the cubic particle. From similar images the mean particle diameter was estimated to be roughly 150 nm and of narrow distribution.

Hereafter the three aging specimens are referred to as follows: unreinforced reference alloy (SAC405), composite with micrometer-scale Cu particles (μmCu + SAC405), and composite with nanometer-scale Cu_2O /PVP particles (nmCu + SAC405). The SAC405 specimen contained three phases upon solidification: a matrix phase and two second phase particles (Fig. 4a). EDS analyses of these phases yielded compositions in weight percent of Sn-4.0Ag, Sn-73Ag, and Sn-40Cu, surmised to be (Sn), Ag_3Sn , and Cu_6Sn_5 , respectively. The Ag_3Sn was organized as a fine needle-like phase within the (Sn) matrix. The Cu_6Sn_5 was observed as both a small fraction of fine particles within the matrix and as a scalloped interfacial layer with the Cu substrate. The average thickness of this Cu_6Sn_5 intermetallic was measured to be 1.4 μm . Though the Cu_3Sn intermetallic is also expected at this interface, it was not resolvable for any of the specimens in the as-soldered condition, an observation in agreement with similar studies.¹⁴ For the μmCu + SAC405 composite specimen a bulk microstructure of the solder alloy with large Ag_3Sn platelets randomly dispersed in the (Sn) matrix was observed. Larger Ag_3Sn platelets extending up to tens of micrometers were found primarily in the vicinity of the Cu reinforcements. The mechanically introduced micrometer-scale Cu particles had also reacted with the solder alloy to form a surrounding Cu_6Sn_5 layer similar to that formed with the Cu substrate (Fig. 5a). The average intermetallic layer thickness at the substrate/solder interface was 1.5 μm . Additionally, pores up to 5 μm in diameter were observed and unique to this specimen. In the nmCu + SAC405 specimen a fine Ag_3Sn needle-like network comparable with that seen in the SAC405's microstructure was observed. Additionally the Cu_2O /PVP nanometer-scale particles appear to have completely transformed into the Cu_6Sn_5 phase (Fig. 6). It is hypothesized that the aggressive flux used during reflow had reduced the copper oxide to copper metal, which subsequently reacted with the solder alloy to form the intermetallic. There was also no evidence of PVP, or its decomposition products, within the bulk of the reflowed solder, though a slight black residue was present on the solder surface that easily washed off following the initial reflow. The average diameter of these particles was roughly 3.5 μm . The average Cu_6Sn_5 layer thickness at the substrate/solder interface for the nmCu + SAC405 specimen was measured to be 1.9 μm .

The aging specimens were re-examined following each heat treatment for interfacial intermetallic layer thickness and microstructural evolution. The interfacial Cu_3Sn phase was only prominent after the first aging interval of 24 h for all specimens. For the SAC405 specimen the fine needle-like Ag_3Sn network observed in the as-soldered condition had been transformed into larger, randomly dispersed Ag_3Sn particles within the (Sn) matrix (Fig. 4b).

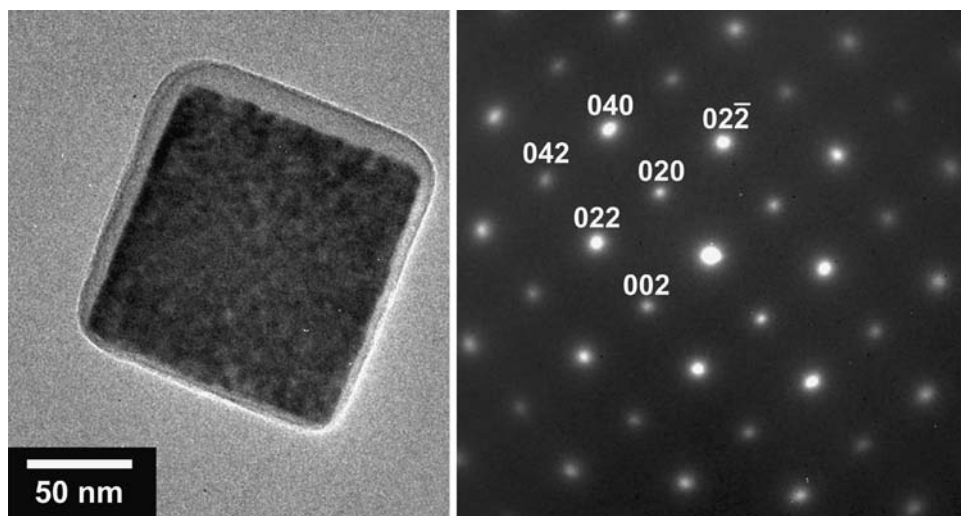


Fig. 3. TEM image and diffraction pattern of the synthesized nanometer-scale Cu_2O particles.

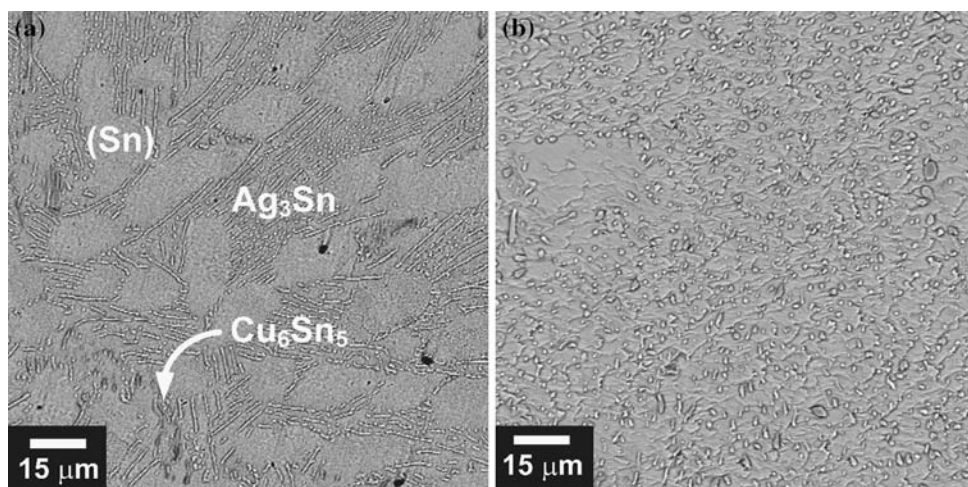


Fig. 4. Backscatter SEM image of the SAC405 specimen in the (a) as-soldered condition and (b) following 144 h at 150°C.

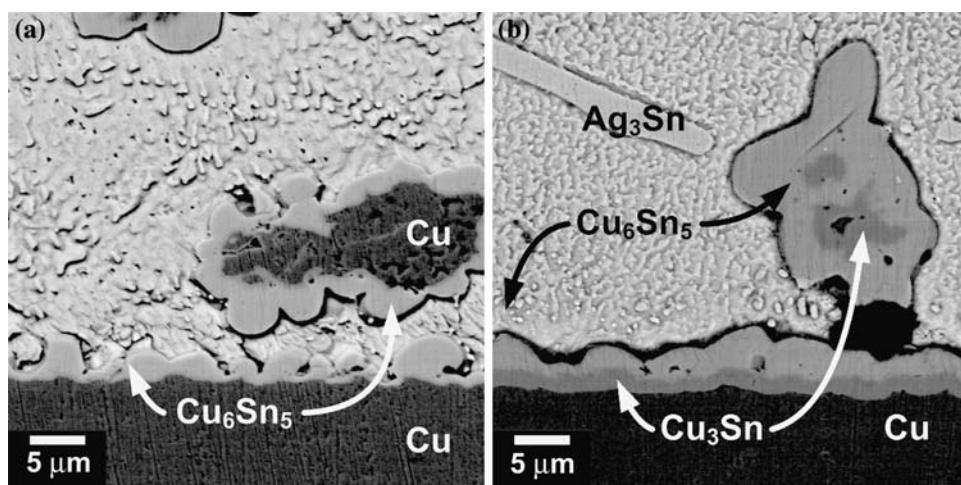


Fig. 5. Backscatter SEM image of the μmCu + SAC405 specimen at the solder/substrate interface in the (a) as-soldered condition and (b) following 144 h at 150°C.

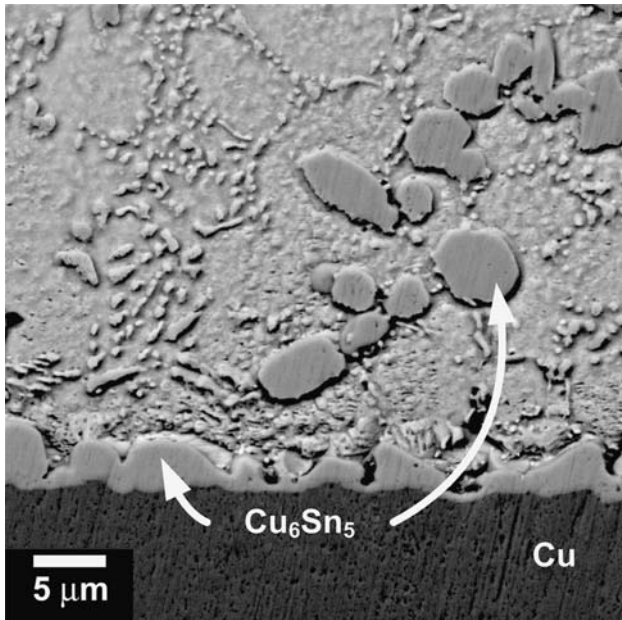


Fig. 6. Backscatter SEM image of the nmCu + SAC405 specimen at the solder/substrate interface in the as-soldered condition.

At the substrate/solder interface, the valleys that were also initially present in between the intermetallic scallops in the as-soldered condition had filled to form a more uniformly thick layer. The total ($\text{Cu}_3\text{Sn} + \text{Cu}_6\text{Sn}_5$) layer thickness for the SAC405 specimen after 144 h of aging was $4.1 \mu\text{m}$. In the $\mu\text{mCu} + \text{SAC405}$ specimen, after aging for 24 h, the transformation of the Cu reinforcements into Cu-Sn intermetallics had increased. Further aging to 144 h increased the consumption of Cu particles by the solder matrix to form a thicker Cu_6Sn_5 surrounding layer (Fig. 5b). The morphology of the interfacial intermetallic at the substrate/solder interface also evolved in a similar fashion to the SAC405 specimen. This total layer thickness was $3.9 \mu\text{m}$ at the conclusion of the 144 h of aging, slightly lower than that measured for the SAC405 specimen. For the nmCu + SAC405 specimen, the original fine Ag_3Sn network evolved similarly to the SAC405 sample to form a coarser structure in the (Sn) matrix. The interfacial intermetallic layer also evolved to be more uniform, with a thickness of $3.8 \mu\text{m}$.

The stress-strain responses of the joints for the as-soldered and aged condition are presented in Figs. 7 and 8, respectively. The solid bulleted curves represent the average stress-strain response of at least three identical specimens. The gray shading represents the range in the measurement. The mechanical response for the specimens tested in the as-soldered condition was very similar for the SAC405 and nmCu + SAC405 specimens. The $\mu\text{mCu} + \text{SAC405}$ specimen, however, exhibits a significantly lower ultimate tensile stress (34.5 MPa) when compared with SAC405 (43.4 MPa) and

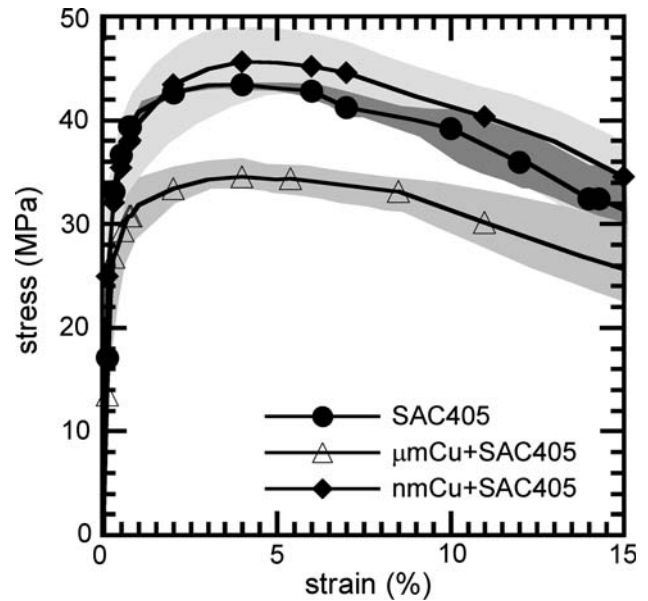


Fig. 7. Tensile stress response for the solders in the as-soldered condition.

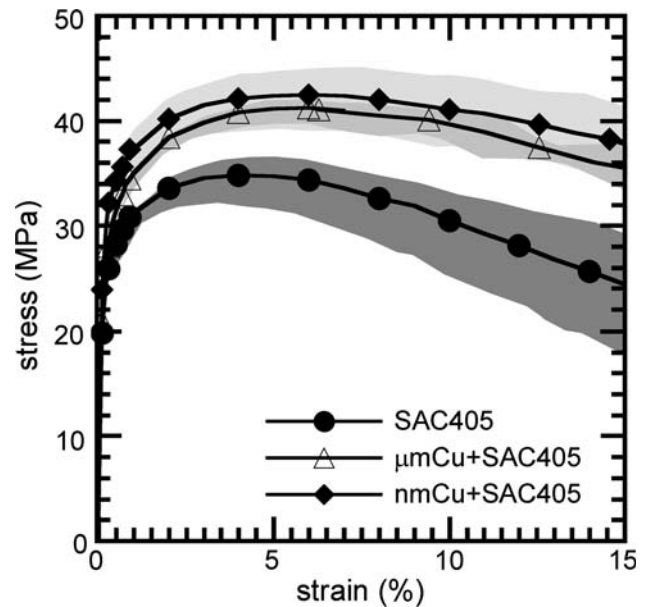


Fig. 8. Tensile stress response for the solders following 24 h of aging.

nmCu + SAC405 (45.6 MPa). In the aged condition the SAC405 specimen's ultimate tensile stress decreased to 34.8 MPa , and the $\mu\text{mCu} + \text{SAC405}$ specimen's increased to 41.2 MPa , comparable with that of the aged nmCu + SAC405 specimen (42.3 MPa) whose mechanical response appeared to be stable through aging. The ductility of the composite specimens also appeared to be unaffected by the presence of the additional reinforcing phase.

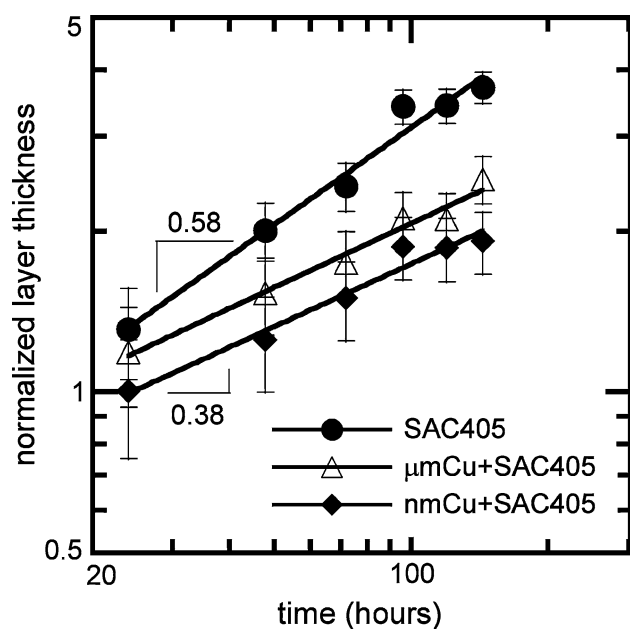


Fig. 9. Normalized interfacial intermetallic layer thickness as a function of aging time.

ANALYSIS AND DISCUSSION

The normalized intermetallic layer thickness at the substrate/solder interface, plotted on a logarithmic scale, are presented in Fig. 9. Since it is the intention of the present study to evaluate the effect of aging on the interfacial intermetallic layer thickness, the measured thickness has been normalized with respect to the as-soldered thickness for comparison between specimens and subsequent analysis. (It is reasonable to expect that small differences in heating and cooling rates and the time during which the solder was molten between specimens could result in large differences in the initial layer thickness.¹⁵ Furthermore, addition of the Cu particles in the composite specimens could have also influenced the solidification temperature, exacerbating this effect.¹⁶) For aging times larger than 24 h, the average thickness follows a power law with aging time with a growth exponent of 0.58, 0.39, and 0.38 for SAC405, $\mu\text{mCu} + \text{SAC405}$, and $\text{nmCu} + \text{SAC405}$, respectively. The separation of the similarly sloped curves for the two composite specimens suggests that a steady state in the growth exponent was not immediately achieved, and therefore the power-law fit would not be valid for shorter times. Additionally, the lower-lying data set for the $\text{nmCu} + \text{SAC405}$ specimen suggests it had reached its steady-state growth exponent sooner than the $\mu\text{mCu} + \text{SAC405}$ specimen.

The growth exponent value of 0.58 for the SAC405 specimen is in agreement with similar works and is indicative of bulk diffusion as the rate-limiting mechanism.¹⁷ The suppression of the interfacial intermetallic layer's growth exponent for the

composite solders suggests that the presence of the additional copper either changes the diffusional mechanism or is in some other way responsible for its reduction. A growth exponent on the order of 0.33, similar to that experienced for the composite solders of this study, is more indicative of a grain-boundary-dominant diffusion as the rate-limiting mechanism.¹⁸ Other hypotheses for the mechanism of growth exponent reduction include the additional Cu particles (i) acting as Sn sinks, thereby reducing the amount of Sn available for the interfacial reaction and (ii) acting as physical obstacles, consequently reducing the cross-sectional area available for Sn diffusion.¹⁹

The similar steady-state growth exponent for the composite solders and the appearance that the $\text{nmCu} + \text{SAC405}$ specimen was first to achieve this steady state provides a basis for further speculation on the rate-limiting mechanism. First, while the $\text{nmCu} + \text{SAC405}$ specimen was fabricated with nanometer-scale $\text{Cu}_2\text{O}/\text{PVP}$ particles, they were quickly converted to micron-sized intermetallic inclusions following the initial reflow. Therefore it is reasonable to expect they might have the same overall effect as the micrometer-scale Cu particles employed in the $\mu\text{mCu} + \text{SAC405}$ specimen, at least for longer aging times. This is indeed what is currently observed, exemplified by the similar steady-state growth exponent for the two composite specimens. The observation that the $\text{nmCu} + \text{SAC405}$ specimen was first to achieve this steady state may then be attributed to the primary difference between the composite specimens: the time to total conversion of the primary particles to the stable Cu_6Sn_5 phase. Since the $\text{Cu}_2\text{O}/\text{PVP}$ particles were converted first and almost completely upon initial reflow, the hypothesis that the particles act as Sn sinks, thereby precluding the full availability of Sn at the substrate/solder interface, is not supported by the current results. However, the hypothesis that the additional particles act as physical obstacles to Sn diffusion towards this interface is reinforced. Since the $\text{Cu}_2\text{O}/\text{PVP}$ particles were quickly converted to the Cu_6Sn_5 phase their maximum volume, and therefore ability to obstruct, was achieved early, providing for an associated early onset of the steady-state growth exponent. Conversely the micrometer-scale Cu particles took longer for their conversion, and therefore attainment of their maximum volume, thereby delaying the onset of a similar steady-state growth exponent.

The trends in specimen strength may be rationalized by considering their microstructure and microstructural evolution through aging. In the as-soldered condition, the two specimens with the similarly high ultimate tensile strength (SAC405 and $\text{nmCu} + \text{SAC405}$) also share a similar microstructural feature: the fine needle-like distribution of the Ag_3Sn phase in the (Sn) matrix. In the $\mu\text{mCu} + \text{SAC405}$ specimen, however, this structure

is absent as the Ag_3Sn is arranged as a coarser phase. Similar studies have also observed higher tensile strengths when the Ag_3Sn particles are more finely dispersed.²⁰ Following aging the fine structure of the Ag_3Sn phase in both the nmCu + SAC405 and SAC405 specimens coarsens, however only the tensile strength of the SAC405 sample decreases. Furthermore, the strength of the μmCu + SAC405 specimen increases to a value comparable with that of the nmCu + SAC405 specimen, even though the Ag_3Sn phase remains as larger platelets. The common feature in the aged condition between the similarly highly strengthened nmCu + SAC405 and μmCu + SAC405 specimens is the presence of the additional Cu_6Sn_5 phase. Unlike in the nmCu + SAC405 specimen, whose strength starts and remains high, the additional aging of the μmCu + SAC405 specimen is required to increase the amount of Cu_6Sn_5 to a level which similarly impacts its mechanical behavior.

CONCLUSION

The microstructural evolution and strength of joints produced with SAC405 lead-free solder depends significantly on reinforcing particle. Solders reinforced with both micrometer- and nanometer-scale reinforcements appear to have reduced the interfacial intermetallic growth rate when compared with unreinforced solder. Furthermore, while a similarly reduced steady-state growth rate exponent is achieved, it is reached first when the reinforcements start as nanometer-scale particles. This behavior is attributed to the smaller reinforcements fully transforming into their equilibrium intermetallic phase before the larger particles. The solder reinforced with the nanometer-scale particles also exhibited the highest strength both before and after aging, without an associated sacrifice in ductility. The unique behavior of this composite comes despite its initially nanometer-scale reinforcements growing to micrometer-scale particles through reflow. The ability to maintain the nanometer scale of the reinforcement may further benefit the properties of this composite solder, and should therefore be considered an outstanding issue for additional work.

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